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3,3',5,5'-Tetrabromo-2,2'-bithiophene

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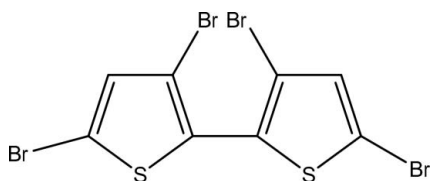
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Key indicators: single-crystal X-ray study; $T = 293$ K; mean $\sigma(\text{C}-\text{C}) = 0.012$ Å; R factor = 0.078; wR factor = 0.208; data-to-parameter ratio = 16.8.

The title compound, $\text{C}_8\text{H}_2\text{Br}_4\text{S}_2$, was prepared by bromination of 2,2'-bithiophene with bromine. The molecule is located on a crystallographic twofold rotation axis, thereby imposing equal geometry of the two thiophene rings. Each five-membered ring is planar [maximum deviation 0.011 (9) Å] and the dihedral angle between the planes through the rings is 47.2 (4)°. The molecules are arranged to minimize intramolecular contacts between the 3-3' and 5-5'-bromine atoms.

Related literature

For use of the title compound as an intermediate in the synthesis of oligothiophenes and polythiophenes, see: Roncali (1997); Funahashi *et al.* (2005). For synthetic methods, see: Takahashi *et al.* (2006); Lin *et al.* (2005).



Experimental

Crystal data

$\text{C}_8\text{H}_2\text{Br}_4\text{S}_2$
 $M_r = 481.86$
Monoclinic, $C2/c$
 $a = 17.164$ (3) Å
 $b = 4.0153$ (7) Å
 $c = 18.655$ (3) Å
 $\beta = 115.395$ (3)°

$V = 1161.4$ (4) Å³
 $Z = 4$
Mo $K\alpha$ radiation
 $\mu = 14.18$ mm⁻¹
 $T = 293$ K
0.40 × 0.17 × 0.05 mm

Data collection

Bruker SMART CCD area-detector diffractometer
Absorption correction: multi-scan (SADABS; Sheldrick, 2004)
 $T_{\min} = 0.258$, $T_{\max} = 1.000$
(expected range = 0.122–0.472)

2792 measured reflections
1077 independent reflections
886 reflections with $I > 2\sigma(I)$
 $R_{\text{int}} = 0.146$

Refinement

$R[F^2 > 2\sigma(F^2)] = 0.078$
 $wR(F^2) = 0.208$
 $S = 1.00$
1077 reflections

64 parameters
H-atom parameters constrained
 $\Delta\rho_{\max} = 1.15$ e Å⁻³
 $\Delta\rho_{\min} = -1.06$ e Å⁻³

Data collection: SMART (Bruker, 2001); cell refinement: SAINT (Bruker, 2001); data reduction: SAINT; program(s) used to solve structure: SHELXS97 (Sheldrick, 2008); program(s) used to refine structure: SHELXL97 (Sheldrick, 2008); molecular graphics: SHELXTL (Sheldrick, 2008); software used to prepare material for publication: SHELXTL.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: KJ2109).

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supporting information

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3,3',5,5'-Tetrabromo-2,2'-bithiophene

Hongqi Li and Lin Li

S1. Comment

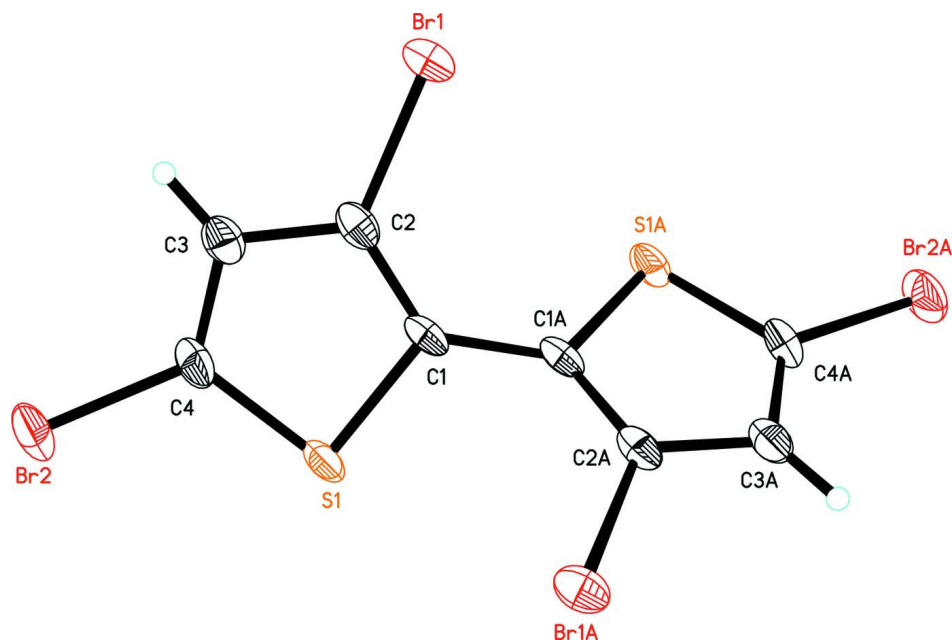
3,3',5,5'-Tetrabromo-2,2'-bithiophene is an important intermediate compound in the synthesis of oligothiophenes and polythiophenes which have recently attracted attention as materials showing conductive, semiconductive, nonlinear optical (NLO), and liquid crystalline characteristics (Roncali, 1997; Funahashi *et al.*, 2005). While synthesis of 3,3',5,5'-tetrabromo-2,2'-bithiophene could be achieved by coupling of 2,3-dibromothiophene (Takahashi *et al.*, 2006) or bromination of 2,2'-bithiophene (Lin *et al.*, 2005), its single crystal structure has not been reported. Herein we present the single crystal structure of the title compound. A molecule of the title compound is located on a crystallographic two-fold rotation axis, thereby imposing equal geometry of the two rings. Each 5-membered ring is planar and the dihedral angle between the planes through the rings is 47.2 (4)°. The molecules arrange in such a fashion that both pairs of bromine atoms (3- and 3'-bromine and 5- and 5'-bromine) lie far away to each other.

S2. Experimental

The title compound was prepared as reported in the literature (Lin *et al.*, 2005). Single crystals suitable for X-ray diffraction measurement were obtained by slow evaporation of a solution in ethanol (m.p. 413 K; literature value: 413–414 K (Takahashi *et al.*, 2006)).

S3. Refinement

All H atoms were placed at calculated positions and refined using a riding model approximation, with C—H = 0.93 Å and with $U_{\text{iso}}(\text{H}) = 1.2U_{\text{eq}}(\text{C})$.

**Figure 1**

A view of the molecule of the title compound. Displacement ellipsoids are drawn at the 30% probability level.

3,3',5,5'-Tetrabromo-2,2'-bithiophene

Crystal data

$C_8H_2Br_4S_2$

$M_r = 481.86$

Monoclinic, $C2/c$

$a = 17.164 (3) \text{ \AA}$

$b = 4.0153 (7) \text{ \AA}$

$c = 18.655 (3) \text{ \AA}$

$\beta = 115.395 (3)^\circ$

$V = 1161.4 (4) \text{ \AA}^3$

$Z = 4$

$F(000) = 888$

Data collection

Bruker SMART CCD area-detector

diffractometer

Radiation source: fine-focus sealed tube

Graphite monochromator

φ and ω scans

Absorption correction: multi-scan

(*SADABS*; Sheldrick, 2004)

$T_{\min} = 0.258$, $T_{\max} = 1.000$

$D_x = 2.756 \text{ Mg m}^{-3}$

Melting point = 413–414 K

Mo $K\alpha$ radiation, $\lambda = 0.71073 \text{ \AA}$

Cell parameters from 1249 reflections

$\theta = 4.8\text{--}55.3^\circ$

$\mu = 14.18 \text{ mm}^{-1}$

$T = 293 \text{ K}$

Prismatic, yellow

$0.40 \times 0.17 \times 0.05 \text{ mm}$

2792 measured reflections

1077 independent reflections

886 reflections with $I > 2\sigma(I)$

$R_{\text{int}} = 0.146$

$\theta_{\max} = 25.5^\circ$, $\theta_{\min} = 2.4^\circ$

$h = -20 \rightarrow 18$

$k = -4 \rightarrow 4$

$l = -22 \rightarrow 21$

Refinement

Refinement on F^2

Least-squares matrix: full

$R[F^2 > 2\sigma(F^2)] = 0.078$

$wR(F^2) = 0.208$

$S = 1.00$

1077 reflections

64 parameters

0 restraints

Primary atom site location: structure-invariant
direct methods

Secondary atom site location: difference Fourier
map

Hydrogen site location: inferred from
neighbouring sites
H-atom parameters constrained

$$w = 1/[\sigma^2(F_o^2) + (0.1428P)^2]$$

where $P = (F_o^2 + 2F_c^2)/3$

$$(\Delta/\sigma)_{\max} < 0.001$$

$$\Delta\rho_{\max} = 1.15 \text{ e } \text{\AA}^{-3}$$

$$\Delta\rho_{\min} = -1.06 \text{ e } \text{\AA}^{-3}$$

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R -factor wR and goodness of fit S are based on F^2 , conventional R -factors R are based on F , with F set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating R -factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. R -factors based on F^2 are statistically about twice as large as those based on F , and R -factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\AA^2)

	<i>x</i>	<i>y</i>	<i>z</i>	$U_{\text{iso}}^*/U_{\text{eq}}$
Br1	0.17755 (6)	0.2991 (3)	0.27753 (6)	0.0443 (5)
Br2	0.11718 (8)	0.7463 (3)	0.54198 (6)	0.0562 (5)
S1	-0.00225 (17)	0.7354 (6)	0.36201 (13)	0.0393 (7)
C1	0.0301 (5)	0.581 (2)	0.2918 (4)	0.0331 (17)
C2	0.1140 (5)	0.480 (2)	0.3291 (4)	0.0354 (17)
C4	0.0973 (6)	0.650 (2)	0.4373 (5)	0.041 (2)
C3	0.1540 (5)	0.521 (2)	0.4129 (4)	0.0411 (19)
H3	0.2109	0.4669	0.4459	0.049*

Atomic displacement parameters (\AA^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
Br1	0.0524 (7)	0.0457 (7)	0.0483 (7)	0.0023 (4)	0.0344 (6)	-0.0050 (4)
Br2	0.0735 (9)	0.0718 (9)	0.0312 (7)	-0.0072 (5)	0.0298 (6)	-0.0063 (4)
S1	0.0508 (15)	0.0482 (13)	0.0306 (12)	0.0043 (9)	0.0286 (11)	-0.0007 (8)
C1	0.050 (5)	0.030 (4)	0.034 (4)	0.000 (4)	0.032 (4)	0.000 (3)
C2	0.052 (5)	0.030 (4)	0.034 (4)	-0.006 (3)	0.028 (4)	0.001 (3)
C4	0.059 (6)	0.042 (5)	0.028 (4)	0.003 (4)	0.025 (4)	0.006 (3)
C3	0.050 (5)	0.046 (5)	0.035 (4)	-0.003 (4)	0.025 (4)	0.005 (4)

Geometric parameters (\AA , $^\circ$)

Br1—C2	1.882 (8)	C1—C1 ⁱ	1.455 (15)
Br2—C4	1.873 (8)	C2—C3	1.422 (11)
S1—C4	1.719 (9)	C4—C3	1.342 (11)
S1—C1	1.741 (7)	C3—H3	0.9300
C1—C2	1.365 (11)		
C4—S1—C1	91.0 (4)	C3—C4—S1	114.3 (6)
C2—C1—C1 ⁱ	131.0 (8)	C3—C4—Br2	126.8 (7)
C2—C1—S1	109.2 (6)	S1—C4—Br2	118.9 (5)

C1 ⁱ —C1—S1	119.8 (7)	C4—C3—C2	109.8 (8)
C1—C2—C3	115.6 (7)	C4—C3—H3	125.1
C1—C2—Br1	124.7 (6)	C2—C3—H3	125.1
C3—C2—Br1	119.6 (6)		
C4—S1—C1—C2	-0.9 (6)	C1—S1—C4—C3	1.7 (7)
C4—S1—C1—C1 ⁱ	179.8 (5)	C1—S1—C4—Br2	-179.2 (5)
C1 ⁱ —C1—C2—C3	179.2 (5)	S1—C4—C3—C2	-1.9 (10)
S1—C1—C2—C3	0.1 (9)	Br2—C4—C3—C2	179.1 (6)
C1 ⁱ —C1—C2—Br1	-0.2 (11)	C1—C2—C3—C4	1.2 (11)
S1—C1—C2—Br1	-179.4 (4)	Br1—C2—C3—C4	-179.4 (6)

Symmetry code: (i) $-x, y, -z+1/2$.